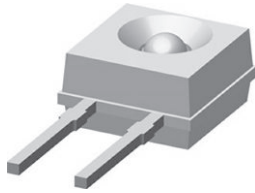




## Infrared Emitting Diode, 950 nm, GaAs



14354

### DESCRIPTION

The TSKS5400S is an infrared, 950 nm emitting diode in GaAs technology with high radiant power, molded in a clear plastic package.

### FEATURES

- Package type: leaded
- Package form: side view lens
- Dimensions (L x W x H in mm): 5 x 2.65 x 5
- Peak wavelength:  $\lambda_p = 950$  nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity:  $\phi = \pm 30^\circ$
- Low forward voltage
- Suitable for high pulse current operation
- Good spectral matching with Si photodetectors
- Package matched with detector TEKS5400
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



### APPLICATIONS

- Photointerrupters
- Transmissive sensors, gap sensors
- Reflective sensors

### PRODUCT SUMMARY

COMPONENT	$I_e$ (mW/sr)	$\phi$ (°)	$\lambda_p$ (nm)	$t_r$ (ns)
TSKS5400S	4.5	$\pm 30$	950	800

#### Note

- Test conditions see table “Basic Characteristics”

### ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TSKS5400S	Bulk	MOQ: 2000 pcs, 2000 pcs/bulk	Side view lens

#### Note

- MOQ: minimum order quantity

### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		$V_R$	6	V
Forward current		$I_F$	100	mA
Surge forward current	$t_p \leq 100 \mu\text{s}$	$I_{FSM}$	2	A
Power dissipation		$P_V$	170	mW
Junction temperature		$T_j$	100	$^\circ\text{C}$
Operating temperature range		$T_{amb}$	-25 to +85	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-40 to +100	$^\circ\text{C}$
Soldering temperature	$t \leq 5$ s, 2 mm from case	$T_{sd}$	260	$^\circ\text{C}$
Thermal resistance junction- to-ambient	J-STD-051, leads 7 mm, soldered on PCB	$R_{thJA}$	270	K/W

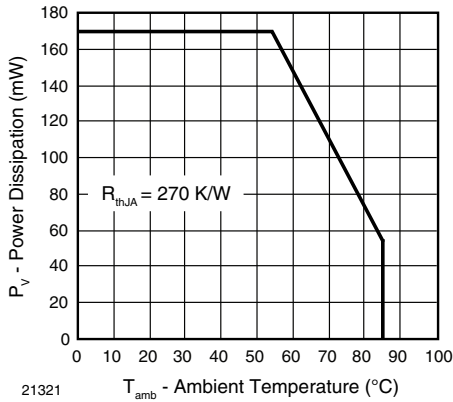


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

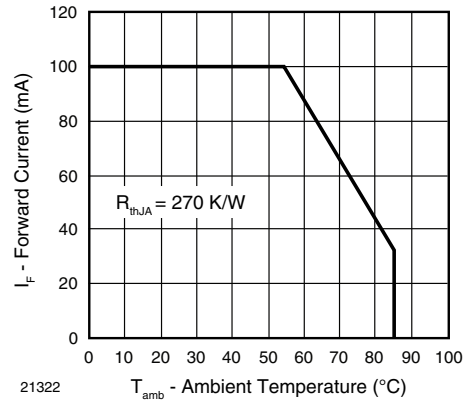


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100\text{ mA}$ , $t_p \leq 20\text{ ms}$	$V_F$	-	1.3	1.7	V
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$	$V_R$	6	-	-	V
Temperature coefficient of $V_F$	$I_F = 100\text{ mA}$	$TK_{V_F}$	-	-1.3	-	mV/K
Junction capacitance	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$	$C_j$	-	50	-	pF
Radiant intensity	$I_F = 100\text{ mA}$ , $t_p \leq 20\text{ ms}$	$I_e$	2	4.5	7	mW/sr
Radiant power	$I_F = 50\text{ mA}$ , $t_p \leq 20\text{ ms}$	$\phi_e$	-	10	-	mW
Temperature coefficient of $\phi_e$	$I_F = 50\text{ mA}$	$TK_{\phi_e}$	-	-1.0	-	%/K
Angle of half sensitivity		$\phi$	-	$\pm 30$	-	$^{\circ}$
Peak wavelength	$I_F = 50\text{ mA}$	$\lambda_p$	-	950	-	nm
Spectral bandwidth	$I_F = 50\text{ mA}$	$\Delta\lambda$	-	50	-	nm
Rise time	$I_F = 100\text{ mA}$	$t_r$	-	800	-	ns
	$I_F = 1\text{ A}$ , $t_p/T = 0.01$ , $t_p \leq 10\text{ }\mu\text{s}$	$t_r$	-	450	-	ns

**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

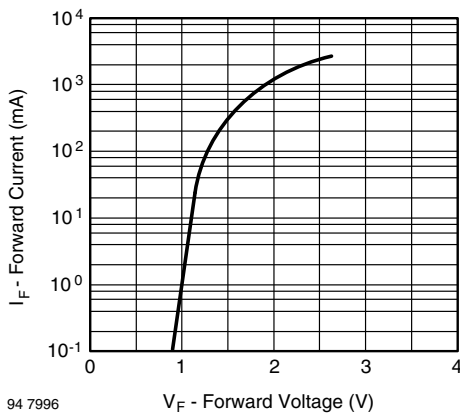


Fig. 3 - Pulse Forward Current vs. Forward Voltage

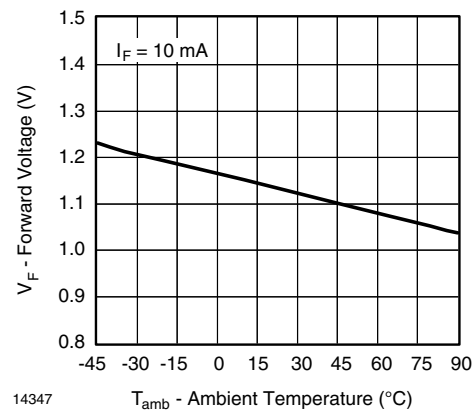


Fig. 4 - Forward Voltage vs. Ambient Temperature

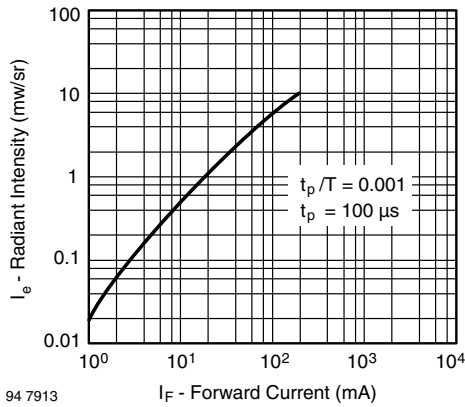


Fig. 5 - Radiant Intensity vs. Forward Current

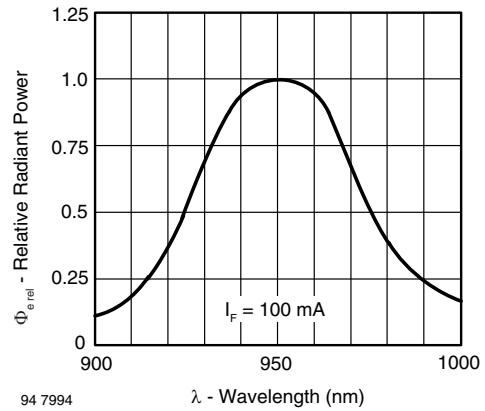


Fig. 8 - Relative Radiant Power vs. Wavelength

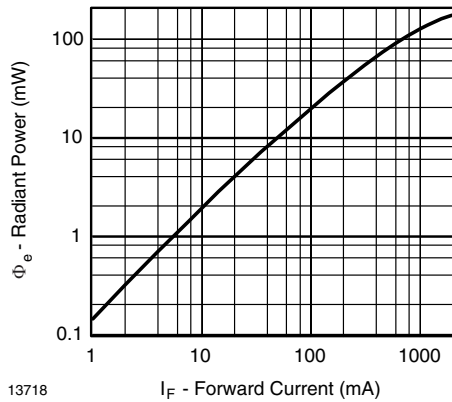


Fig. 6 - Radiant Power vs. Forward Current

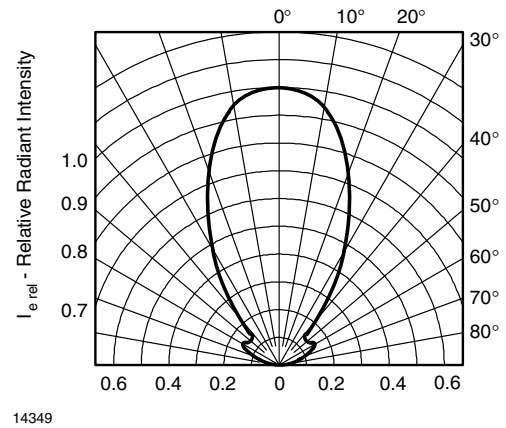


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

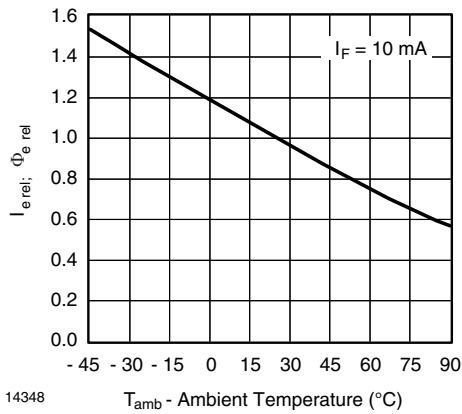
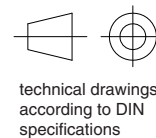
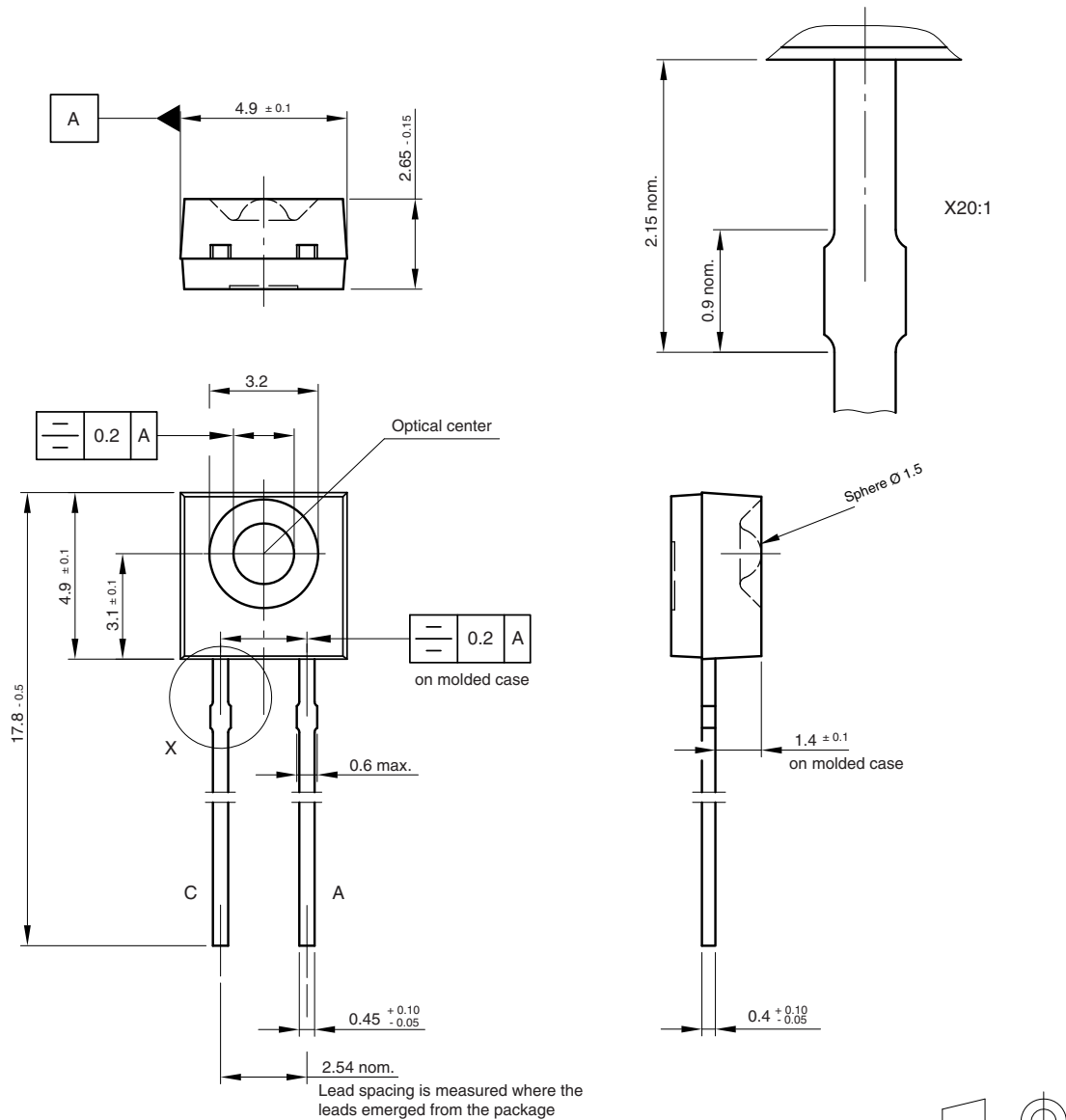


Fig. 7 - Relative Radiant Intensity vs. Ambient Temperature



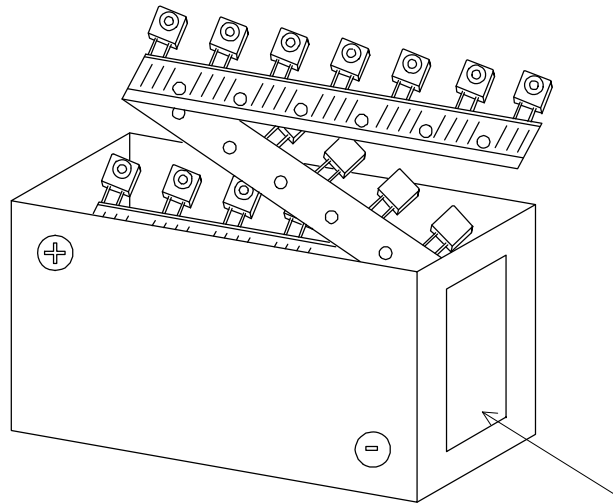
PACKAGE DIMENSIONS in millimeters



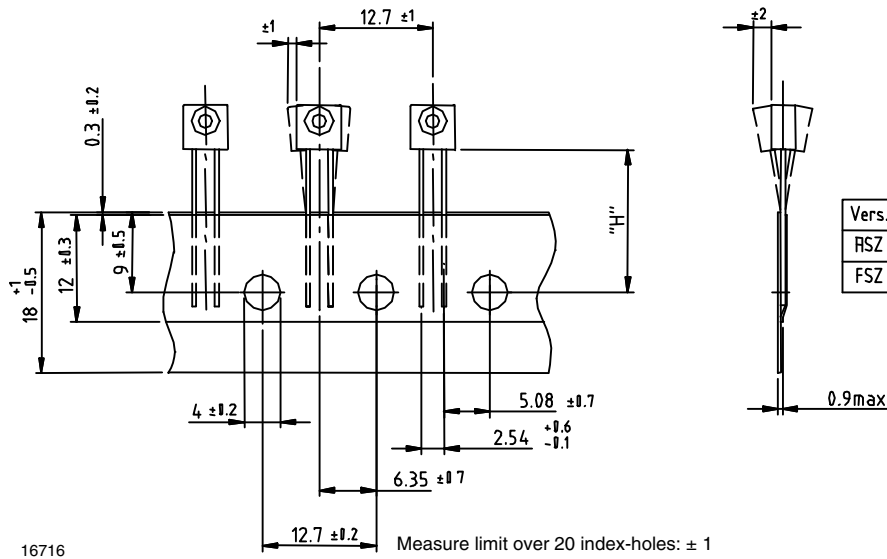
Drawing-No.: 6.544-5306.51-4  
 Issue: 6; 04.07.02  
 14307



**TAPE AND AMMOPACK STANDARDS DIMENSIONS** in millimeters



Labeling: barcode-label see 5.6.4



Vers.	Dim. "H"
RSZ	16 ± 0.5
FSZ	27 ± 0.5

16716



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